



(11) **EP 2 927 975 B8**

(12) **CORRECTED EUROPEAN PATENT SPECIFICATION**

(15) Correction information:
Corrected version no 1 (W1 B1)
Corrections, see
Bibliography INID code(s) 72

(51) Int Cl.:
H01L 45/00 ^(2006.01)

(48) Corrigendum issued on:
15.08.2018 Bulletin 2018/33

(45) Date of publication and mention
of the grant of the patent:
30.05.2018 Bulletin 2018/22

(21) Application number: **14186833.1**

(22) Date of filing: **29.09.2014**

(54) **Resistive random access memory and method of fabricating the same**

Resistiver Direktzugriffsspeicher und Verfahren zur Herstellung davon

Mémoire vive résistive et son procédé de fabrication

(84) Designated Contracting States:
AL AT BE BG CH CY CZ DE DK EE ES FI FR GB
GR HR HU IE IS IT LI LT LU LV MC MK MT NL NO
PL PT RO RS SE SI SK SM TR

(30) Priority: **02.04.2014 TW 103112331**

(43) Date of publication of application:
07.10.2015 Bulletin 2015/41

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